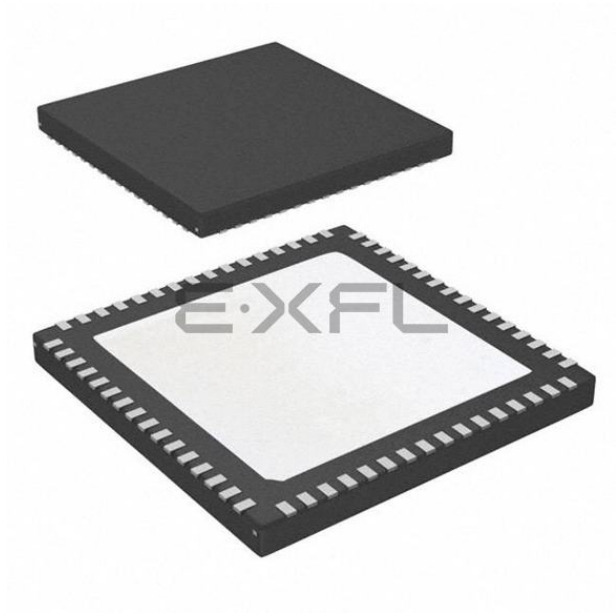
Renesas Electronics America Inc - R7FS3A17C3A01CNB#AC0 Datasheet



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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, EBI/EMI, I²C, MMC/SD, QSPI, SCI, SSIE, SPI, UART/USART, USB
Peripherals	DMA, LCD, LVD, POR, PWM, WDT
Number of I/O	52
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	8K x 8
RAM Size	192K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 18x14b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-WFQFN Exposed Pad
Supplier Device Package	64-HWQFN (8x8)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r7fs3a17c3a01cnb-ac0

Table 1.7 Timers

Feature	Functional description
General PWM Timer (GPT)	The GPT is a 32-bit timer with four channels and a 16-bit timer with six channels. PWM waveforms can be generated by controlling the up-counter, down-counter, or the up- and down-counter. In addition, PWM waveforms can be generated for controlling brushless DC motors. The GPT can also be used as a general-purpose timer. See section 23, General PWM Timer (GPT) in User's Manual.
Port Output Enable for GPT (POEG)	Use the POEG function to place the General PWM Timer (GPT) output pins in the output disable state. See section 22, Port Output Enable for GPT (POEG) in User's Manual.
Asynchronous General Purpose Timer (AGT)	The AGT is a 16-bit timer that can be used for pulse output, external pulse width or period measurement, and counting external events. This 16-bit timer consists of a reload register and a down-counter. The reload register and the down-counter are allocated to the same address, and they can be accessed with the AGT register. See section 24, Asynchronous General Purpose Timer (AGT) in User's Manual.
Realtime Clock (RTC)	The RTC has two counting modes, calendar count mode and binary count mode, that are controlled by the register settings. For calendar count mode, the RTC has a 100-year calendar from 2000 to 2099 and automatically adjusts dates for leap years. For binary count mode, the RTC counts seconds and retains the information as a serial value. Binary count mode can be used for calendars other than the Gregorian (Western) calendar. See section 25, Realtime Clock (RTC) in User's Manual.

Table 1.8 Communication interfaces (1 of 2)

Feature	Functional description
Serial Communications Interface (SCI)	The SCI is configurable to five asynchronous and synchronous serial interfaces: • Asynchronous interfaces (UART and asynchronous communications interface adapter (ACIA)) • 8-bit clock synchronous interface • Simple IIC (master-only) • Simple SPI • Smart card interface. The smart card interface complies with the ISO/IEC 7816-3 standard for electronic signals and transmission protocol. SCI0 and SCI1 have FIFO buffers to enable continuous and full-duplex communication, and the data transfer speed can be configured independently using an on-chip baud rate generator. See section 29, Serial Communications Interface (SCI) in User's Manual.
I^2C Bus Interface (IIC)	The 3-channel IIC module conforms with and provides a subset of the NXP I^2C bus (Inter-Integrated Circuit bus) interface functions. See section 30, I^2C Bus Interface (IIC) in User's Manual.
Serial Peripheral Interface (SPI)	Two independent SPI channels are capable of high-speed, full-duplex synchronous serial communications with multiple processors and peripheral devices. See section 32, Serial Peripheral Interface (SPI) in User's Manual.
Serial Sound Interface Enhanced (SSIE)	The SSIE peripheral provides functionality to interface with digital audio devices for transmitting PCM audio data over a serial bus with the MCU. The SSIE supports an audio clock frequency of up to 25 MHz, and can be operated as a slave or master receiver, transmitter, or transceiver to suit various applications. The SSIE includes 8-stage FIFO buffers in the receiver and transmitter, and supports interrupts and DMA-driven data reception and transmission. See section 35, Serial Sound Interface Enhanced (SSIE) in User's Manual.
Quad Serial Peripheral Interface (QSPI)	The QSPI is a memory controller for connecting a serial ROM (nonvolatile memory such as a serial flash memory, serial EEPROM, or serial FeRAM) that has an SPI-compatible interface. See section 33, Quad Serial Peripheral Interface (QSPI) in User's Manual.
Controller Area Network (CAN) Module	The CAN module provides functionality to receive and transmit data using a message-based protocol between multiple slaves and masters in electromagnetically noisy applications. The CAN module complies with the ISO 11898-1 (CAN 2.0A/CAN 2.0B) standard and supports up to 32 mailboxes, which can be configured for transmission or reception in normal mailbox and FIFO modes. Both standard (11-bit) and extended (29-bit) messaging formats are supported. See section 31, Controller Area Network (CAN) Module in User's Manual.

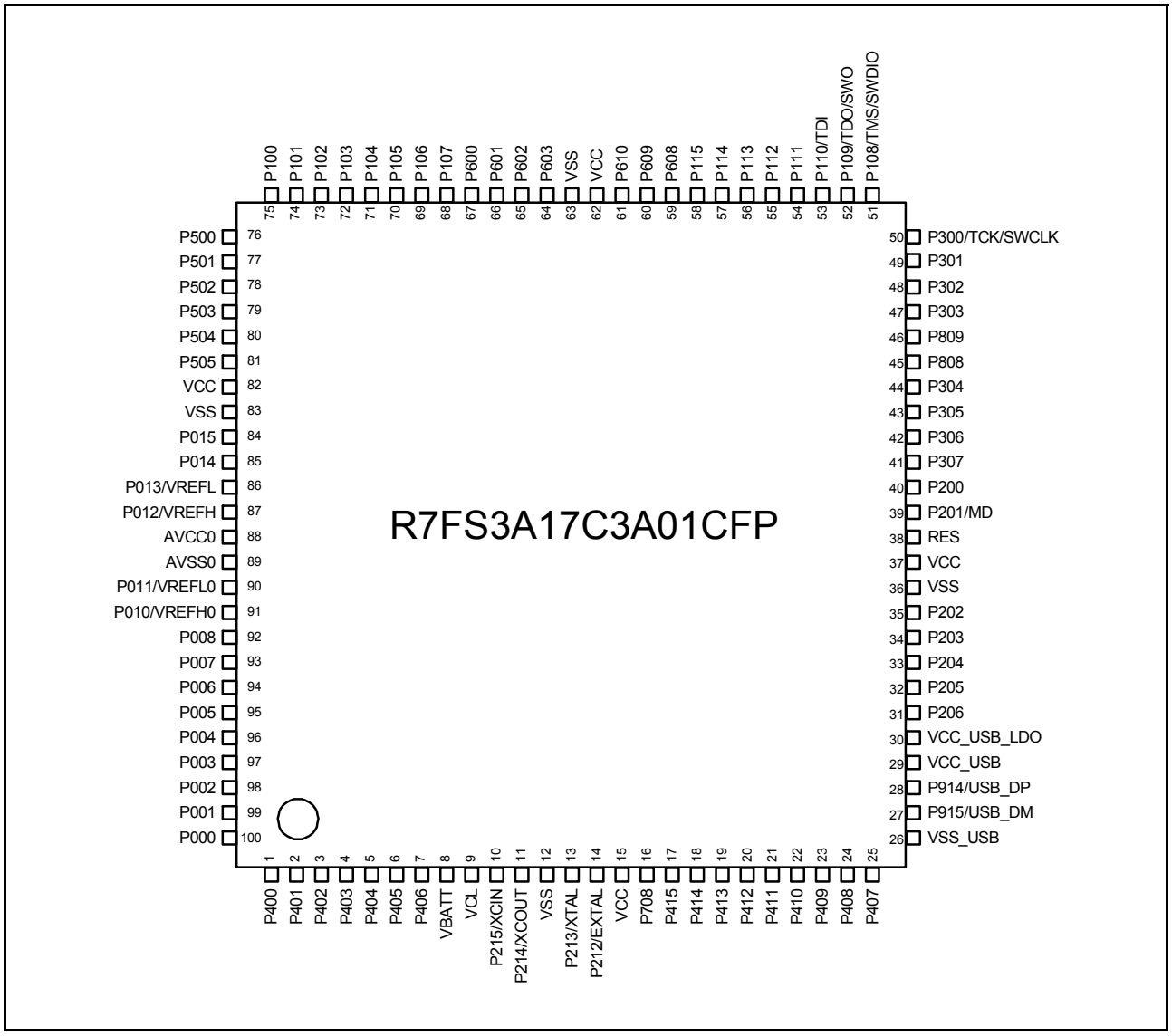


Figure 1.6 Pin assignment for 100-pin LQFP (top view)

2. Electrical Characteristics

Unless otherwise specified, the electrical characteristics of the MCU are defined under the following conditions:

VCC*1 = AVCC0 = VCC_USB*2 = VCC_USB_LDO*2 = 1.6 to 5.5 V, VRERH = VREFH0 = 1.6 to AVCC0, VBATT = 1.6 to 3.6 V, VSS = AVSS0 = VREFL = VREFL0 = VSS_USB = 0 V, Ta = T_{opr}.

Note 1. The typical condition is set to VCC = 3.3V.
Note 2. When USBFS is not used.

Figure 2.1 shows the timing conditions.

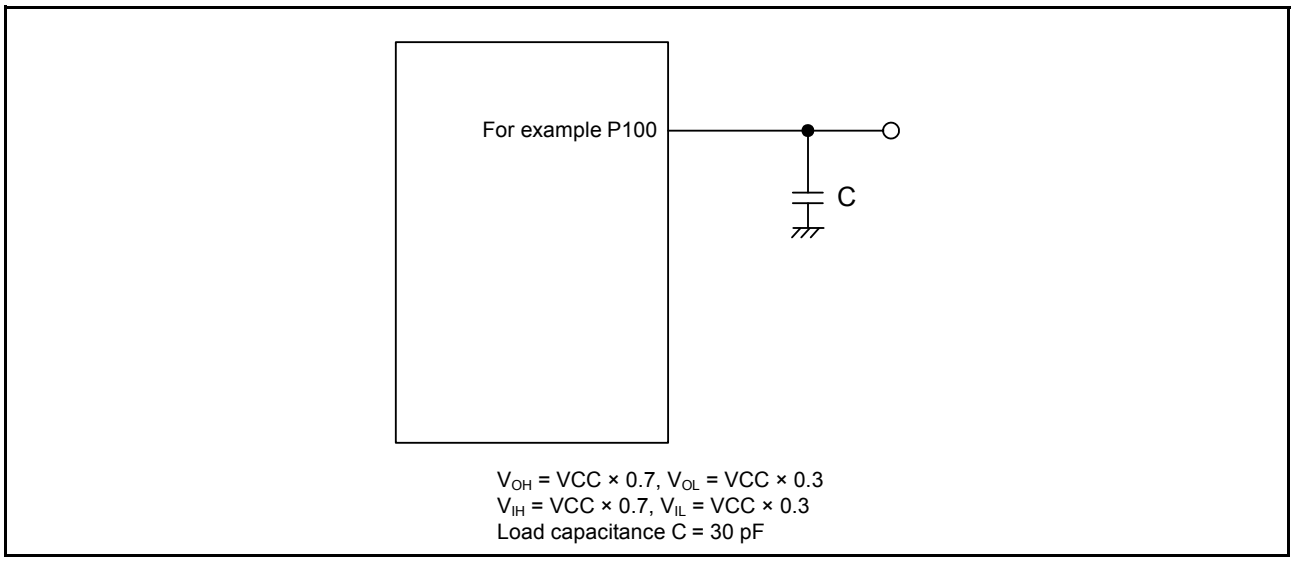


Figure 2.1 Input or output timing measurement conditions

The measurement conditions of timing specifications in each peripheral are recommended for the best peripheral operation. However, make sure to adjust driving abilities of each pin to meet your conditions.

Each function pin used for the same function must select the same drive ability. If the I/O drive ability of each function pin is mixed, the AC specification of each function is not guaranteed.

Table 2.22 Clock timing (2 of 2)

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
HOCO clock oscillation frequency		f_{HOCO24}	23.64	24	24.36	MHz	Ta = –40 to –20°C 1.8 ≤ VCC ≤ 5.5
			22.68	24	25.32		Ta = –40 to 85°C 1.6 ≤ VCC < 1.8
			23.76	24	24.24		Ta = –20 to 85°C 1.8 ≤ VCC ≤ 5.5
			23.52	24	24.48		Ta = 85 to 105°C 2.4 ≤ VCC ≤ 5.5
		f_{HOCO32}	31.52	32	32.48		Ta = –40 to -20°C 1.8 ≤ VCC ≤ 5.5
			30.24	32	33.76		Ta = –40 to 85°C 1.6 ≤ VCC < 1.8
			31.68	32	32.32		Ta = –20 to 85°C 1.8 ≤ VCC ≤ 5.5
			31.36	32	32.64		Ta = 85 to 105°C 2.4 ≤ VCC ≤ 5.5
		f_{HOCO48}*4	47.28	48	48.72		Ta = –40 to –20°C 1.8 ≤ VCC ≤ 5.5
			47.52	48	48.48		Ta = –20 to 85°C 1.8 ≤ VCC ≤ 5.5
			47.04	48	48.96		Ta = 85 to 105°C 2.4 ≤ VCC ≤ 5.5
		f_{HOCO64}*5	63.04	64	64.96		Ta = –40 to –20°C 2.4 ≤ VCC ≤ 5.5
			63.36	64	64.64		Ta = –20 to 85°C 2.4 ≤ VCC ≤ 5.5
			62.72	64	65.28		Ta = 85 to 105°C 2.4 ≤ VCC ≤ 5.5
HOCO clock oscillation stabilization time*6, *7	Except Low-voltage mode	t_{HOCO24} t_{HOCO32}	-	-	37.1	µs	Figure 2.29
		t_{HOCO48}	-	-	43.3		
		t_{HOCO64}	-	-	80.6		
	Low-voltage mode	t_{HOCO24} t_{HOCO32} t_{HOCO48} t_{HOCO64}	-	-	100.9		
PLL input frequency*2		f_{PLLIN}	4	-	12.5	MHz	-
PLL circuit oscillation frequency*2		f_{PLL}	24	-	64	MHz	-
PLL clock oscillation stabilization time*8		t_{PLL}	-	-	55.5	µs	Figure 2.31
PLL free-running oscillation frequency		f_{PLLFR}	-	8	-	MHz	-
Sub-clock oscillator oscillation frequency		f_{SUB}	-	32.768	-	kHz	-
Sub-clock oscillation stabilization time*3		t_{SUBOSC}	-	-	-*3	s	Figure 2.32

Note 1. Time until the clock can be used after the Main Clock Oscillator Stop bit (MOSCCR.MOSTP) is set to 0 (operating) when the external clock is stable.
Note 2. The VCC range that the PLL can be used is 2.4 to 5.5 V.
Note 3. After changing the setting of the SOSCCR.SOSTP bit so that the sub-clock oscillator operates, only start using the sub-clock oscillator after the sub-clock oscillation stabilization wait time elapsed. Use the oscillator wait time recommended by the oscillator manufacturer.
Note 4. The 48-MHz HOCO can be used within a VCC range of 1.8 V to 5.5 V.
Note 5. The 64-MHz HOCO can be used within a VCC range of 2.4 V to 5.5 V.
Note 6. This is a characteristic when HOCOCR.HCSTP bit is set to 0 (oscillation) in MOCO stop state.
When HOCOCR.HCSTP bit is set to 0 (oscillation) during MOCO oscillation, this specification is shortened by 1 µs.
Note 7. Whether stabilization time has elapsed can be confirmed by OSCSF.HOCOSF.
Note 8. This is a characteristic when PLLCR.PLLSTP bit is set to 0 (operation) in MOCO stop state.
When PLLCR.PLLSTP bit is set to 0 (operation) during MOCO oscillation, this specification is shortened by 1 µs.
Note 9. When setting up the main clock, ask the oscillator manufacturer for an oscillation evaluation and use the results as the recommended oscillation stabilization time. Set the MOSCWTCR register to a value equal to or greater than the recommended stabilization time. After changing the setting of the MOSCCR.MOSTP bit so that the main clock oscillator operates, read the OSCSF.MOSCSF flag to confirm that it is 1, then start using the main clock.

Table 2.26 Timing of recovery from low power modes (3)

Parameter				Symbol	Min	Typ	Max	Unit	Test conditions
Recovery time from Software Standby mode*1	Low-speed mode	Crystal resonator connected to main clock oscillator	System clock source is main clock oscillator (1 MHz)*2	t_{SBYMC}	-	2	3	ms	Figure 2.36
		External clock input to main clock oscillator	System clock source is main clock oscillator (1 MHz)*3	t_{SBYEX}	-	28	50	µs	
		System clock source is MOCO		t_{SBYMO}	-	25	35	µs	

Note 1. The division ratio of ICK, BCK, FCK, and PCKx is the minimum division ratio within the allowable frequency range. The recovery time is determined by the system clock source.
Note 2. The Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 05h.
Note 3. The Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 00h.

Table 2.27 Timing of recovery from low power modes (4)

Parameter				Symbol	Min	Typ	Max	Unit	Test conditions
Recovery time from Software Standby mode*1	Low-voltage mode	Crystal resonator connected to main clock oscillator	System clock source is main clock oscillator (4 MHz)*2	t_{SBYMC}	-	2	3	ms	Figure 2.36
		External clock input to main clock oscillator	System clock source is main clock oscillator (4 MHz)*3	t_{SBYEX}	-	108	130	µs	
		System clock source is HOCO		t_{SBYHO}	-	108	130	µs	

Note 1. The division ratio of ICK, BCK, FCK, and PCKx is the minimum division ratio within the allowable frequency range. The recovery time is determined by the system clock source. When multiple oscillators are active, the recovery time can be determined by the following expression.
Note 2. The Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 05h.
Note 3. The Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 00h.

Table 2.28 Timing of recovery from low power modes (5)

Parameter			Symbol	Min	Typ	Max	Unit	Test conditions
Recovery time from Software Standby mode*1	Subosc-speed mode	System clock source is sub-clock oscillator (32.768 kHz)	t_{SBYSC}	-	0.85	1	ms	Figure 2.36
		System clock source is LOCO (32.768 kHz)	t_{SBYLO}	-	0.85	1.2	ms	

Note 1. The sub-clock oscillator or LOCO itself continues to oscillate in Software Standby mode during Subosc-speed mode.

2.3.6 Bus Timing

Table 2.31 Bus timing (1)
Conditions: Low drive output is selected in the Port Drive Capability in PmnPFS register
VCC = 2.7 to 5.5 V
Output load conditions: V_{OH} = VCC × 0.5, V_{OL} = VCC × 0.5, C = 30 pF

Parameter	Symbol	Min	Max	Unit	Test conditions
Address delay	t_{AD}	-	55	ns	Figure 2.42 to Figure 2.45
Byte control delay	t_{BCD}	-	55	ns	
CS delay	t_{CSD}	-	55	ns	
ALE delay time	t_{ALED}	-	55	ns	
RD delay	t_{RSD}	-	55	ns	
Read data setup time	t_{RDS}	37	-	ns	
Read data hold time	t_{RDH}	0	-	ns	
WR delay	t_{WRD}	-	55	ns	
Write data delay	t_{WDD}	-	55	ns	
Write data hold time	t_{WDH}	0	-	ns	
WAIT setup time	t_{WTS}	37	-	ns	Figure 2.46
WAIT hold time	t_{WTH}	0	-	ns	

Table 2.32 Bus timing (2)
Conditions: Low drive output is selected in the Port Drive Capability in PmnPFS register
VCC = 2.4 to 2.7 V
Output load conditions: V_{OH} = VCC × 0.5, V_{OL} = VCC × 0.5, C = 30 pF

Parameter	Symbol	Min	Max	Unit	Test conditions
Address delay	t_{AD}	-	55	ns	Figure 2.42 to Figure 2.45
Byte control delay	t_{BCD}	-	55	ns	
CS delay	t_{CSD}	-	55	ns	
ALE delay time	t_{ALED}	-	55	ns	
RD delay	t_{RSD}	-	55	ns	
Read data setup time	t_{RDS}	45	-	ns	
Read data hold time	t_{RDH}	0	-	ns	
WR delay	t_{WRD}	-	55	ns	
Write data delay	t_{WDD}	-	55	ns	
Write data hold time	t_{WDH}	0	-	ns	
WAIT setup time	t_{WTS}	45	-	ns	Figure 2.46
WAIT hold time	t_{WTH}	0	-	ns	

2.3.9 SCI Timing

Table 2.37 SCI timing (1)

Parameter				Symbol	Min	Max	Unit*1	Test conditions
SCI	Input clock cycle	Asynchronous		t_{Scyc}	4	-	t_{Pcyc}	Figure 2.53
		Clock synchronous			6	-		
	Input clock pulse width			t_{SCKW}	0.4	0.6	t_{Scyc}	
	Input clock rise time			t_{SCKr}	-	20	ns	
	Input clock fall time			t_{SCKf}	-	20	ns	
	Output clock cycle	Asynchronous		t_{Scyc}	6	-	t_{Pcyc}	
		Clock synchronous			4	-		
	Output clock pulse width			t_{SCKW}	0.4	0.6	t_{Scyc}	
	Output clock rise time		1.8 V or above	t_{SCKr}	-	20	ns	
			1.6 V or above		-	30		
	Output clock fall time		1.8 V or above	t_{SCKf}	-	20	ns	
			1.6 V or above		-	30		
	Transmit data delay (master)	Clock synchronous	1.8 V or above	t_{TXD}	-	40	ns	Figure 2.54
			1.6 V or above		-	45		
	Transmit data delay (slave)	Clock synchronous	2.7 V or above		-	55	ns	
			2.4 V or above		-	60		
			1.8 V or above		-	100		
			1.6 V or above		-	125		
	Receive data setup time (master)	Clock synchronous	2.7 V or above	t_{RXS}	45	-	ns	
			2.4 V or above		55	-		
			1.8 V or above		90	-		
			1.6 V or above		110	-		
	Receive data setup time (slave)	Clock synchronous	2.7 V or above		40	-	ns	
			1.6 V or above		45	-		
	Receive data hold time (master)	Clock synchronous		t_{RXH}	5	-	ns	
	Receive data hold time (slave)	Clock synchronous		t_{RXH}	40	-	ns	

Note 1. t_{Pcyc}: PCLKA cycle.

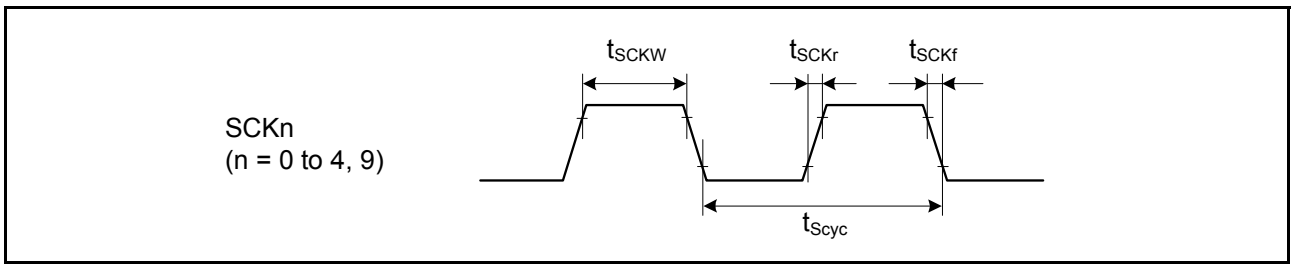


Figure 2.53 SCK clock input timing

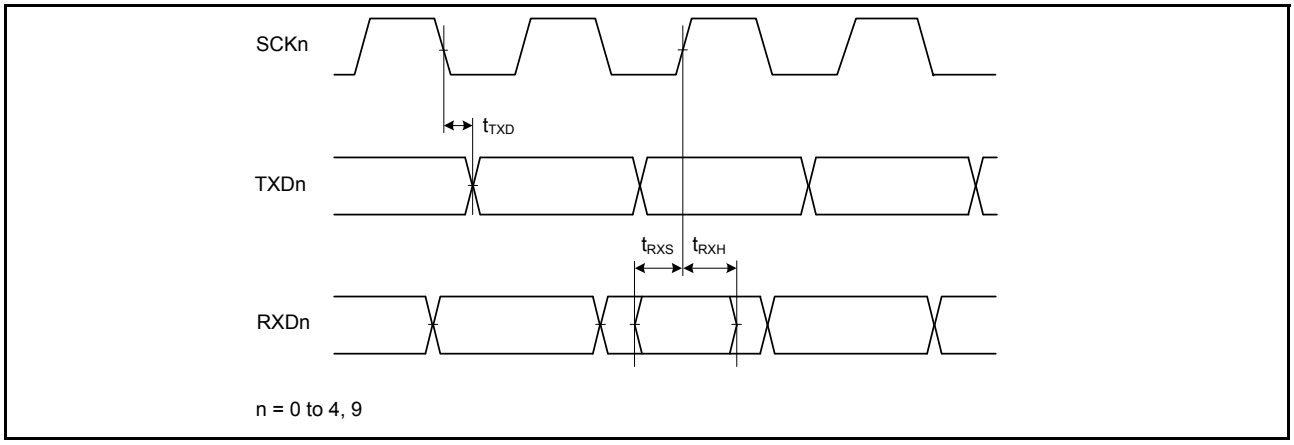


Figure 2.54 SCI input/output timing in clock synchronous mode

Table 2.38 SCI timing (2) (1 of 2)

Parameter				Symbol	Min	Max	Unit	Test conditions
Simple SPI	SCK clock cycle output (master)			t_{SPcyc}	4	65536	t_{Pcyc}	Figure 2.55
	SCK clock cycle input (slave)				6	65536		
	SCK clock high pulse width			t_{SPCKWH}	0.4	0.6	t_{SPcyc}	
	SCK clock low pulse width			t_{SPCKWL}	0.4	0.6	t_{SPcyc}	
	SCK clock rise and fall time		1.8 V or above	t_{SPCKr}, t_{SPCKf}	-	20	ns	
			1.6 V or above		-	30		
	Data input setup time	Master	2.7 V or above	t_{SU}	45	-	ns	Figure 2.56 to Figure 2.59
			2.4 V or above		55	-		
			1.8 V or above		80	-		
			1.6 V or above		110	-		
		Slave	2.7 V or above		40	-		
			1.6 V or above		45	-		
	Data input hold time	Master		t_{H}	33.3	-	ns	
		Slave			40	-		
	SS input setup time			t_{LEAD}	1	-	t_{SPcyc}	
	SS input hold time			t_{LAG}	1	-	t_{SPcyc}	
	Data output delay	Master	1.8 V or above	t_{OD}	-	40	ns	
			1.6 V or above		-	50		
		Slave	2.4 V or above		-	65		
			1.8 V or above		-	100		
			1.6 V or above		-	125		
	Data output hold time	Master	2.7 V or above	t_{OH}	–10	-	ns	
			2.4 V or above		–20	-		
			1.8 V or above		–30	-		
			1.6 V or above		–40	-		
		Slave			–10	-		
	Data rise and fall time	Master	1.8 V or above	t_{Dr}, t_{Df}	-	20	ns	
			1.6 V or above		-	30		
		Slave	1.8 V or above		-	20		
			1.6 V or above		-	30		

Table 2.38 SCI timing (2) (2 of 2)

Parameter		Symbol	Min	Max	Unit	Test conditions
Simple SPI	Slave access time	t_{SA}	-	10 (PCLKA > 32 MHz), 6 (PCLKA ≤ 32 MHz)	t_{Pcyc}	Figure 2.58 and Figure 2.59
	Slave output release time	t_{REL}	-	10 (PCLKA > 32 MHz), 6 (PCLKA ≤ 32 MHz)	t_{Pcyc}	

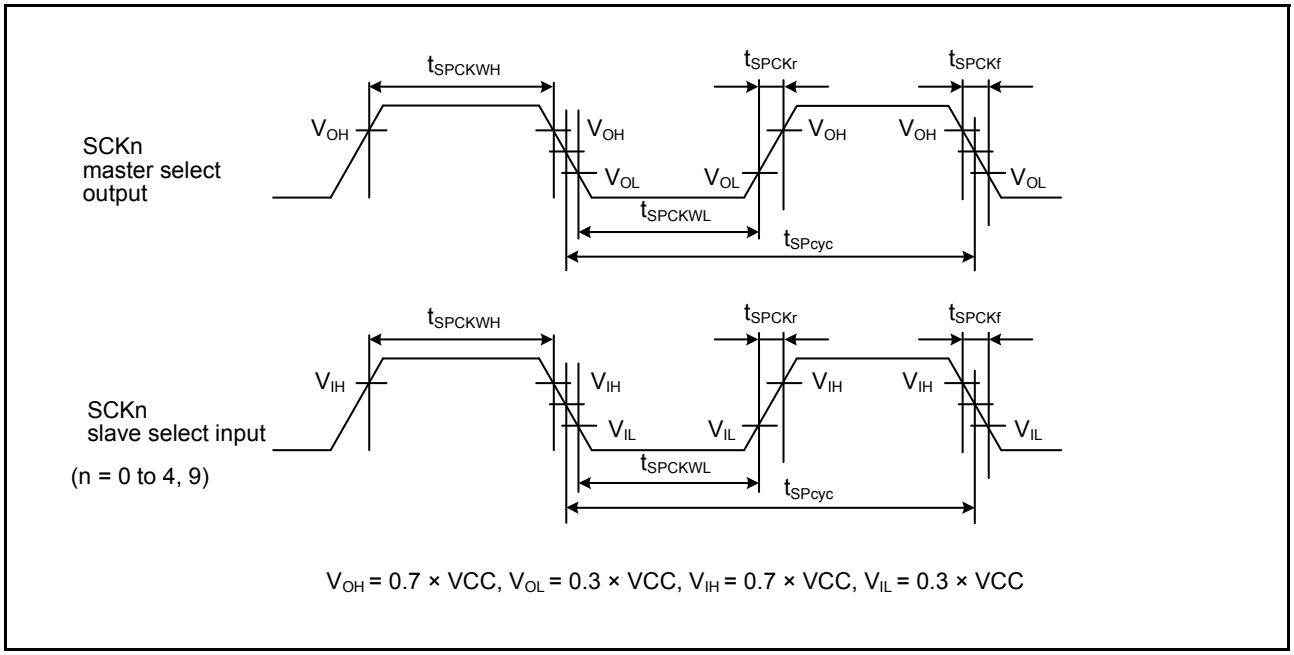


Figure 2.55 SCI simple SPI mode clock timing

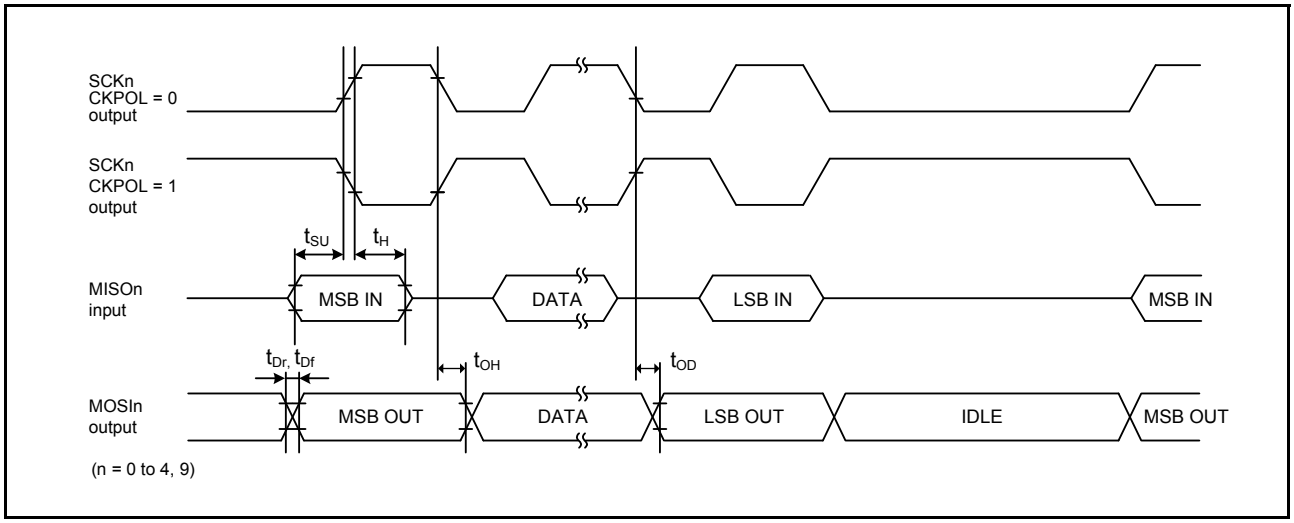


Figure 2.56 SCI simple SPI mode timing (master, CKPH = 1)

Table 2.40 SPI timing (2 of 2)

Conditions: Middle drive output is selected in the Port Drive Capability in PmnPFS register

Parameter				Symbol	Min	Max	Unit*1	Test conditions
SPI	Data output delay	Master	2.7 V or above	t_{OD}	-	14	ns	Figure 2.62 to Figure 2.67
			2.4 V or above		-	20		
			1.8 V or above		-	25		
			1.6 V or above		-	30		
		Slave	2.7 V or above		-	50		
			2.4 V or above		-	60		
			1.8 V or above		-	85		
			1.6 V or above		-	110		
	Data output hold time	Master		t_{OH}	0	-	ns	
		Slave			0	-		
	Successive transmission delay	Master		t_{TD}	$t_{SPcyc} + 2 \times t_{Pcyc}$	$8 \times t_{SPcyc} + 2 \times t_{Pcyc}$	ns	
		Slave			$6 \times t_{Pcyc}$	-		
	MOSI and MISO rise and fall time	Output	2.7 V or above	t_{Dr}, t_{Df}	-	10	ns	
			2.4 V or above		-	15		
			1.8 V or above		-	20		
			1.6 V or above		-	30		
		Input			-	1	µs	
	SSL rise and fall time	Output	2.7 V or above	t_{SSLr}, t_{SSLf}	-	10	ns	
			2.4 V or above		-	15		
			1.8 V or above		-	20		
			1.6 V or above		-	30		
		Input			-	1	µs	
	Slave access time		2.4 V or above	t_{SA}	-	$2 \times t_{Pcyc} + 100$	ns	Figure 2.66 and Figure 2.67
			1.8 V or above		-	$2 \times t_{Pcyc} + 140$		
			1.6 V or above		-	$2 \times t_{Pcyc} + 180$		
	Slave output release time		2.4 V or above	t_{REL}	-	$2 \times t_{Pcyc} + 100$	ns	
			1.8 V or above		-	$2 \times t_{Pcyc} + 140$		
			1.6 V or above		-	$2 \times t_{Pcyc} + 180$		

Note 1. t_{Pcyc}: PCLKA cycle.
Note 2. N is set as an integer from 1 to 8 by the SPCKD register.
Note 3. N is set as an integer from 1 to 8 by the SSLND register.
Note 4. The upper limit of RSPCK is 16 MHz.

2.3.12 IIC Timing

Table 2.42 IIC timing
Conditions: VCC = 2.7 to 5.5 V

Parameter		Symbol	Min*1	Max	Unit	Test conditions
IIC (standard mode, SMBus)	SCL input cycle time	t_{SCL}	6 (12) × t_{IICcyc} + 1300	-	ns	Figure 2.70
	SCL input high pulse width	t_{SCLH}	3 (6) × t_{IICcyc} + 300	-	ns	
	SCL input low pulse width	t_{SCLL}	3 (6) × t_{IICcyc} + 300	-	ns	
	SCL, SDA input rise time	t_{Sr}	-	1000	ns	
	SCL, SDA input fall time	t_{Sf}	-	300	ns	
	SCL, SDA input spike pulse removal time	t_{SP}	0	1 (4) × t_{IICcyc}	ns	
	SDA input bus free time (When wakeup function is disabled)	t_{BUF}	3 (6) × t_{IICcyc} + 300	-	ns	
	SDA input bus free time (When wakeup function is enabled)	t_{BUF}	3 (6) × t_{IICcyc} + 4 × t_{Pcyc} + 300	-	ns	
	START condition input hold time (When wakeup function is disabled)	t_{STAH}	t_{IICcyc} + 300	-	ns	
	START condition input hold time (When wakeup function is enabled)	t_{STAH}	1 (5) × t_{IICcyc} + t_{Pcyc} + 300	-	ns	
	Repeated START condition input setup time	t_{STAS}	1000	-	ns	
	STOP condition input setup time	t_{STOS}	1000	-	ns	
	Data input setup time	t_{SDAS}	t_{IICcyc} + 50	-	ns	
	Data input hold time	t_{SDAH}	0	-	ns	
	SCL, SDA capacitive load	C_b	-	400	pF	
IIC (Fast mode)	SCL input cycle time	t_{SCL}	6 (12) × t_{IICcyc} + 600	-	ns	Figure 2.70 For all ports except P408, use PmnPFS.DSCR of middle drive. For port P408, use PmnPFS.DSCR 1/DSCR of middle drive for IIC fast-mode.
	SCL input high pulse width	t_{SCLH}	3 (6) × t_{IICcyc} + 300	-	ns	
	SCL input low pulse width	t_{SCLL}	3 (6) × t_{IICcyc} + 300	-	ns	
	SCL, SDA input rise time	t_{Sr}	-	300	ns	
	SCL, SDA input fall time	t_{Sf}	-	300	ns	
	SCL, SDA input spike pulse removal time	t_{SP}	0	1 (4) × t_{IICcyc}	ns	
	SDA input bus free time (When wakeup function is disabled)	t_{BUF}	3 (6) × t_{IICcyc} + 300	-	ns	
	SDA input bus free time (When wakeup function is enabled)	t_{BUF}	3 (6) × t_{IICcyc} + 4 × t_{Pcyc} + 300	-	ns	
	START condition input hold time (When wakeup function is disabled)	t_{STAH}	t_{IICcyc} + 300	-	ns	
	START condition input hold time (When wakeup function is enabled)	t_{STAH}	1(5) × t_{IICcyc} + t_{Pcyc} + 300	-	ns	
	Repeated START condition input setup time	t_{STAS}	300	-	ns	
	STOP condition input setup time	t_{STOS}	300	-	ns	
	Data input setup time	t_{SDAS}	t_{IICcyc} + 50	-	ns	
	Data input hold time	t_{SDAH}	0	-	ns	
	SCL, SDA capacitive load	C_b	-	400	pF	

Note: t_{IICcyc}: IIC internal reference clock (IICφ) cycle, t_{Pcyc}: PCLKB cycle
Note 1. The value in parentheses apply when ICMR3.NF[1:0] is set to 11b while the digital filter is enabled with ICFER.NFE set to 1.

2.3.13 SSIE Timing

Table 2.43 SSIE timing
Conditions: VCC = 1.6 to 5.5 V

Parameter			Symbol	Min	Max	Unit	Test conditions
SSIE	AUDIO_CLK input frequency	2.7 V or above	t_{AUDIO}	-	25	MHz	-
		1.6 V or above		-	4		
	Output clock period		t_O	250	-	ns	Figure 2.71
	Input clock period		t_I	250	-	ns	
	Clock high pulse width	1.8 V or above	t_{HC}	100	-	ns	
		1.6 V or above		200	-		
	Clock low pulse width	1.8 V or above	t_{LC}	100	-	ns	
		1.6 V or above		200	-		
	Clock rise time		t_{RC}	-	25	ns	
	Data delay	2.7 V or above	t_{DTR}	-	65	ns	Figure 2.72, Figure 2.73
		1.8 V or above		-	105		
		1.6 V or above		-	140		
	Set-up time	2.7 V or above	t_{SR}	65	-	ns	
		1.8 V or above		90	-		
		1.6 V or above		140	-		
	Hold time		t_{HTR}	40	-	ns	
	SSITXD0 output delay from SSILRCK/SSIFS change time	1.8 V or above	t_{DTRW}	-	105	ns	Figure 2.74
		1.6 V or above		-	140		

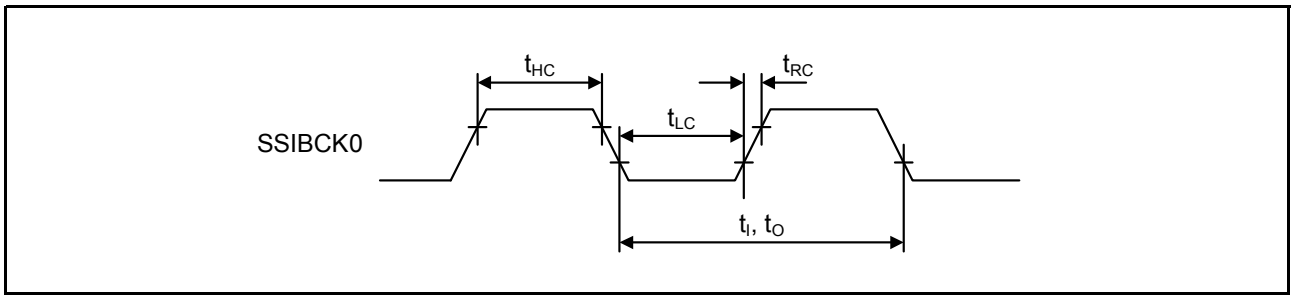


Figure 2.71 SSIE clock input/output timing

2.6 DAC12 Characteristics

Table 2.57 D/A conversion characteristics (1)
Conditions: VCC = AVCC0 = 1.8 to 5.5 V
Reference voltage = VREFH or VREFL selected

Parameter	Min	Typ	Max	Unit	Test conditions
Resolution	-	-	12	bit	-
Resistive load	30	-	-	kΩ	-
Capacitive load	-	-	50	pF	-
Output voltage range	0.35	-	AVCC0 – 0.47	V	-
DNL differential nonlinearity error	-	±0.5	±1.0	LSB	-
INL integral nonlinearity error	-	±2.0	±8.0	LSB	-
Offset error	-	-	±20	mV	-
Full-scale error	-	-	±20	mV	-
Output impedance	-	5	-	Ω	-
Conversion time	-	-	30	µs	-

Table 2.58 D/A conversion characteristics (2)
Conditions: VCC = AVCC0 = 1.8 to 5.5 V
Reference voltage = AVCC0 or AVSS0 selected

Parameter	Min	Typ	Max	Unit	Test conditions
Resolution	-	-	12	bit	-
Resistive load	30	-	-	kΩ	-
Capacitive load	-	-	50	pF	-
Output voltage range	0.35	-	AVCC0 – 0.47	V	-
DNL differential nonlinearity error	-	±0.5	±2.0	LSB	-
INL integral nonlinearity error	-	±2.0	±8.0	LSB	-
Offset error	-	-	±30	mV	-
Full-scale error	-	-	±30	mV	-
Output impedance	-	5	-	Ω	-
Conversion time	-	-	30	µs	-

Table 2.59 D/A conversion characteristics (3)
Conditions: VCC = AVCC0 = 1.8 to 5.5 V
Reference voltage = internal reference voltage selected

Parameter	Min	Typ	Max	Unit	Test conditions
Resolution	-	-	12	bit	-
Internal reference voltage (Vbgr)	1.36	1.43	1.50	V	-
Resistive load	30	-	-	kΩ	-
Capacitive load	-	-	50	pF	-
Output voltage range	0.35	-	Vbgr	V	-
DNL differential nonlinearity error	-	±2.0	±16.0	LSB	-
INL integral nonlinearity error	-	±8.0	±16.0	LSB	-
Offset error	-	-	±30	mV	-
Output impedance	-	5	-	Ω	-
Conversion time	-	-	30	µs	-

Table 2.63 Power-on reset circuit and voltage detection circuit characteristics (2)

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
Wait time after power-on reset cancellation	LVD0: enable	t_{POR}	-	1.7	-	ms	-
	LVD0: disable	t_{POR}	-	1.3	-	ms	-
Wait time after voltage monitor 0, 1, 2 reset cancellation	LVD0: enable*1	$t_{LVD0,1,2}$	-	0.6	-	ms	-
	LVD0: disable*2	$t_{LVD1,2}$	-	0.2	-	ms	-
Response delay*3		t_{det}	-	-	350	µs	Figure 2.85, Figure 2.86
Minimum VCC down time		t_{VOFF}	450	-	-	µs	Figure 2.85, VCC = 1.0 V or above
Power-on reset enable time		$t_{W(POR)}$	1	-	-	ms	Figure 2.86, VCC = below 1.0 V
LVD operation stabilization time (after LVD is enabled)		$t_{d(E-A)}$	-	-	300	µs	Figure 2.88, Figure 2.89
Hysteresis width (POR)		V_{PORH}	-	110	-	mV	-
Hysteresis width (LVD0, LVD1, and LVD2)		V_{LVH}	-	60	-	mV	LVD0 selected
			-	100	-		V_{det1_0} to V_{det1_2} selected
			-	60	-		V_{det1_3} to V_{det1_9} selected
			-	50	-		V_{det1_A} or V_{det1_B} selected
			-	40	-		V_{det1_C} or V_{det1_F} selected
			-	60	-		LVD2 selected

Note 1. When OFS1.LVDAS = 0.
Note 2. When OFS1.LVDAS = 1.
Note 3. The minimum VCC down time indicates the time when VCC is below the minimum value of voltage detection levels V_{POR}, V_{det0}, V_{det1}, and V_{det2} for the POR/LVD.

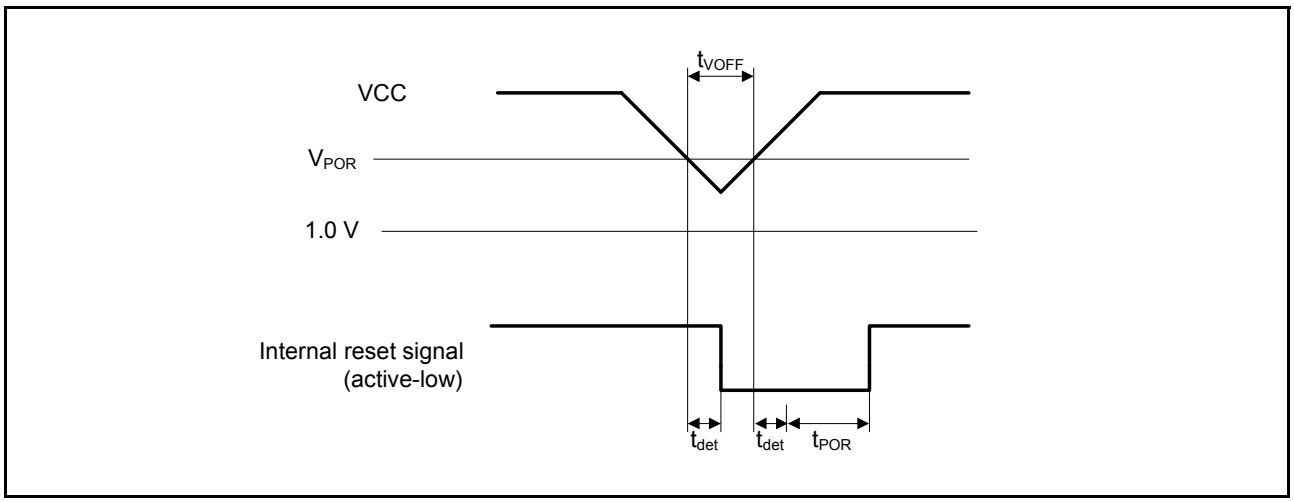


Figure 2.85 Voltage detection reset timing

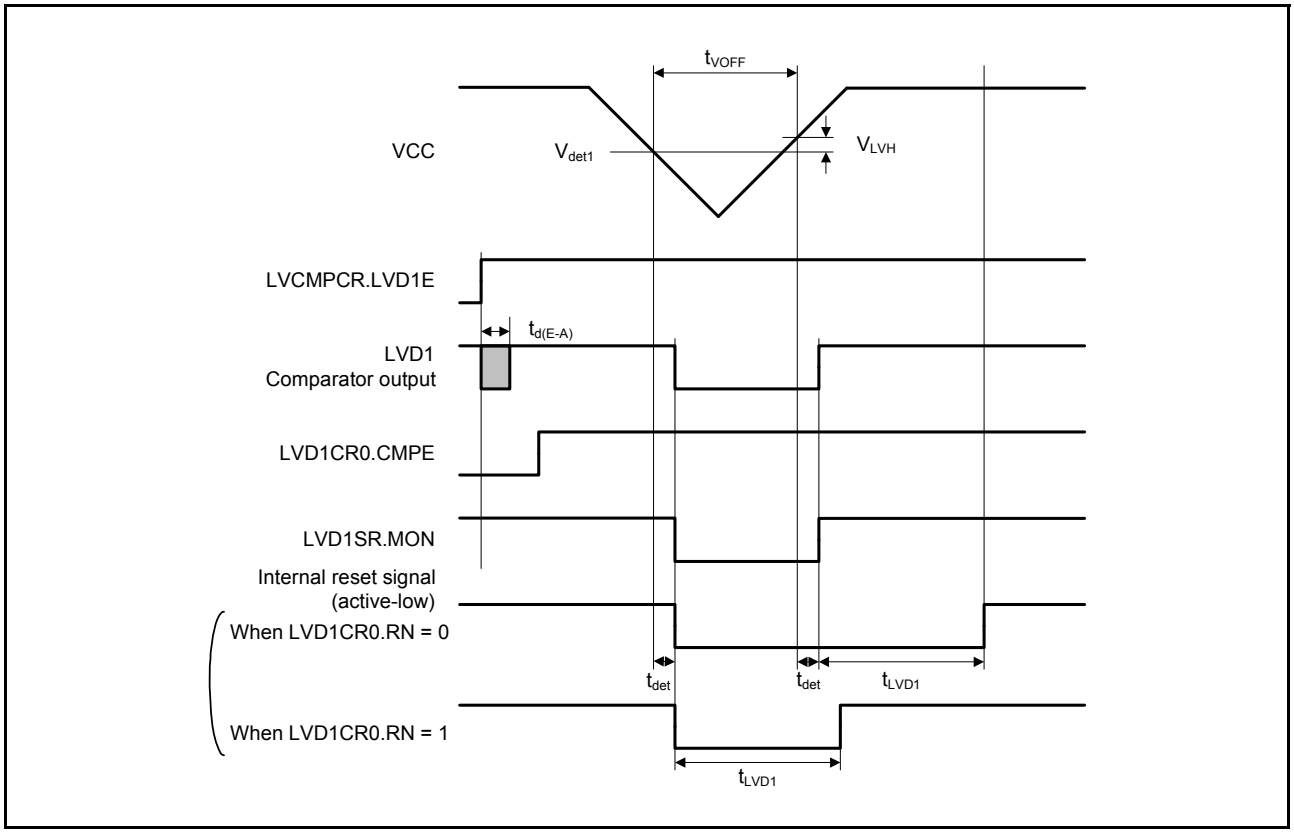


Figure 2.88 Voltage detection circuit timing (V_{det1})

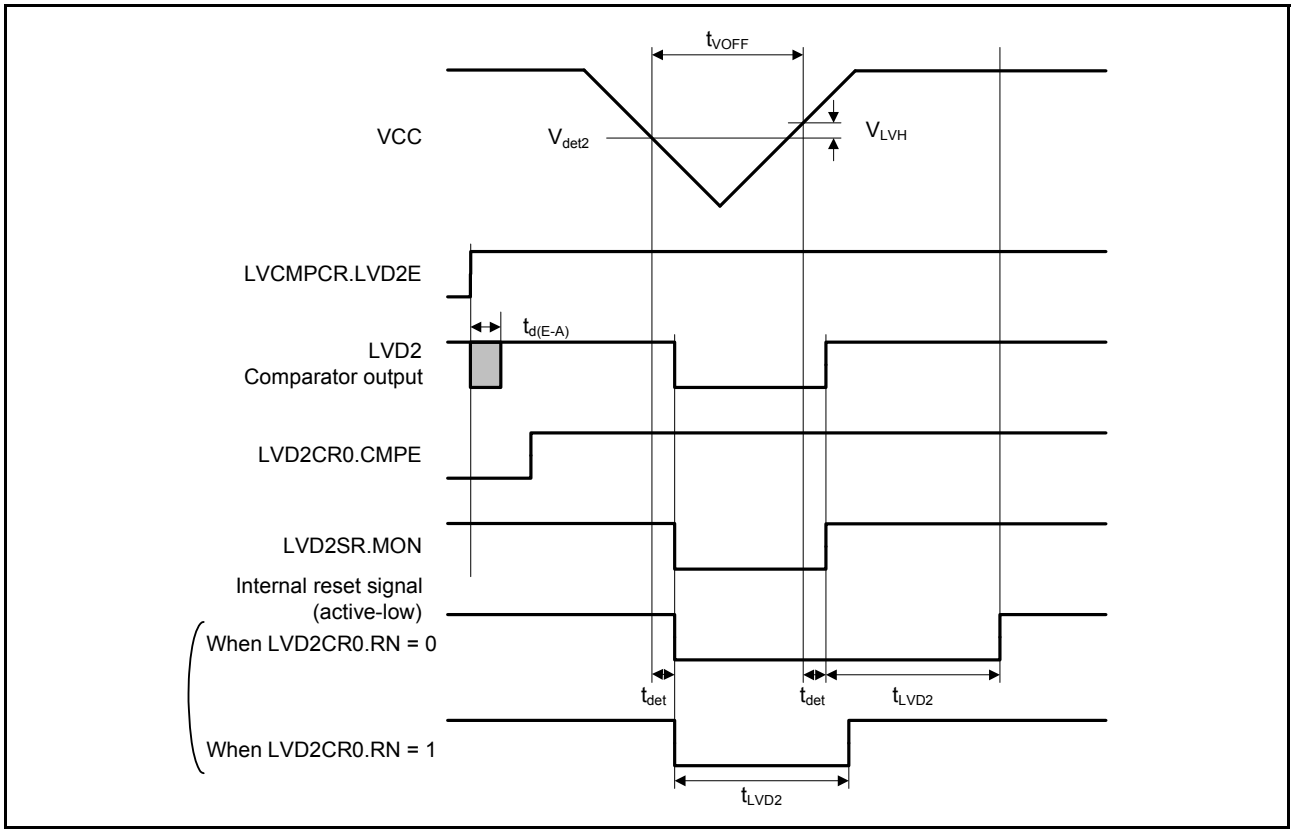


Figure 2.89 Voltage detection circuit timing (V_{det2})

2.10 VBATT Characteristics

Table 2.64 Battery backup function characteristics
Conditions: VCC = AVCC0 = 1.6 V to 5.5 V, VBATT = 1.6 to 3.6 V

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
Voltage level for switching to battery backup (falling)		$V_{DETBATT}$	1.99	2.09	2.19	V	Figure 2.90, Figure 2.91
Hysteresis width for switching to battery back up		V_{VBATTH}	-	100	-	mV	
VCC-off period for starting power supply switching		$t_{VOFFBATT}$	300	-	-	µs	-
Voltage detection level VBATT_Power-on reset (VBATT_POR)		$V_{VBATPOR}$	1.30	1.40	1.50	V	Figure 2.90, Figure 2.91
Wait time after VBATT_POR reset time cancellation		$t_{VBATPOR}$	-	-	3	mS	-
Level for detection of voltage drop on the VBATT pin (falling)	VBTLVDLVL[1:0] = 10b	$V_{DETBATLVD}$	2.11	2.2	2.29	V	Figure 2.92
	VBTLVDLVL[1:0] = 11b		1.92	2	2.08	V	
Hysteresis width for VBATT pin LVD		$V_{VBATLVDTH}$	-	50	-	mV	
VBATT pin LVD operation stabilization time		t_{d_vbat}	-	-	300	µs	Figure 2.92
VBATT pin LVD response delay time		t_{det_vbat}	-	-	350	µs	
Allowable voltage change rising/falling gradient		dt/dVCC	1.0	-	-	ms/V	-
VCC voltage level for access to the VBATT backup registers		$V_{\_BKBATT}$	1.8	-	-	V	-

Note: The VCC-off period for starting power supply switching indicates the period in which VCC is below the minimum value of the voltage level for switching to battery backup ($V_{DETBATT}$).

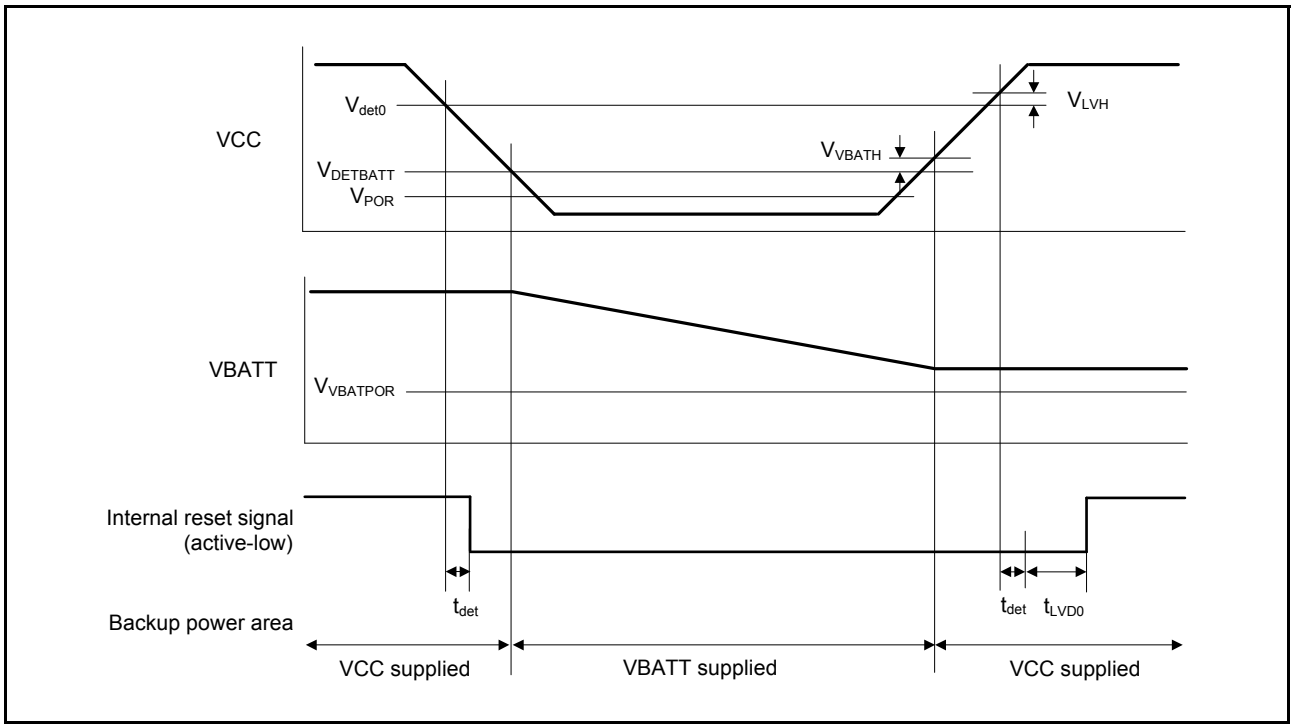


Figure 2.90 Power supply switching and LVD0 reset timing

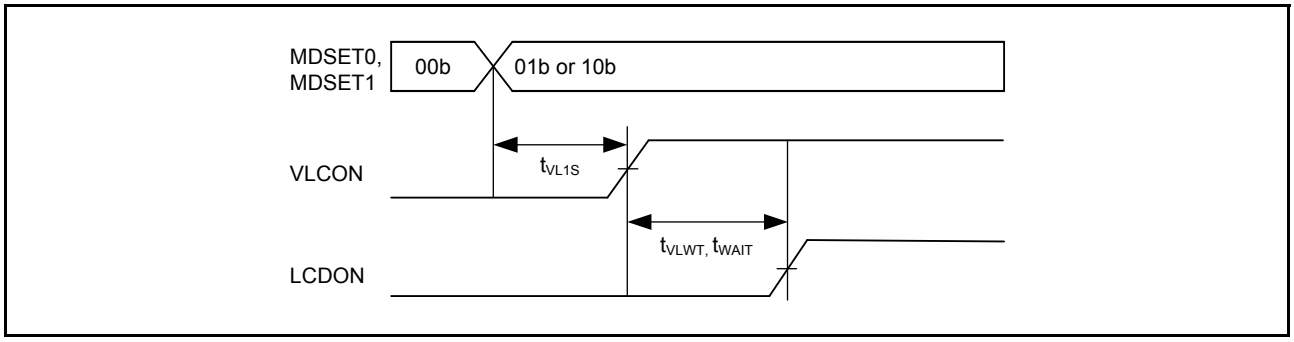


Figure 2.93 LCD reference voltage setup time, voltage boosting wait time, and capacitor split wait time

2.13 Comparator Characteristics

Table 2.73 ACMPLP characteristics
Conditions: VCC = 1.8 to 5.5 V

Parameter			Symbol	Min	Typ	Max	Unit	Test conditions
Reference voltage range	Standard mode	IVREFn (n = 0,1)	VREF	0	-	VCC - 1.4	V	-
	Window mode*2	IVREF1	VREFH	1.4	-	VCC	V	-
		IVREF0	VREFL	0	-	VCC - 1.4	V	-
Input voltage range			VI	0	-	VCC	V	-
Internal reference voltage			-	1.36	1.44	1.50	V	-
Output delay	High-speed mode		Td	-	-	1.2	µs	VCC = 3.0 Slew rate of input signal > 50 mV/µs
	Low-speed mode			-	-	5	µs	
	Window mode			-	-	2	µs	
Offset voltage*1	High-speed mode		-	-	-	50	mV	-
	Low-speed mode		-	-	-	40	mV	-
	Window mode		-	-	-	60	mV	-
Operation stabilization wait time			T_{cmp}	100	-	-	µs	-

Note 1. When 8-bit DAC output is used as the reference voltage, the offset voltage increases up to 2.5 × VCC/256.
Note 2. In window mode, be sure to satisfy the following condition: IVREF1 - IVREF0 ≥ 0.2 V.

2.14 OPAMP Characteristics

Table 2.74 OPAMP characteristics (1 of 2)
Conditions: VCC = AVCC0 = 1.8 to 5.5 V (AVCC0 = VCC when VCC < 2.0 V)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Common mode input range	Vicm1	Low-power mode	0.2	-	AVCC0 – 0.5	V
	Vicm2	High-speed mode	0.3	-	AVCC0 – 0.6	V
Output voltage range	Vo1	Low-power mode	0.1	-	AVCC0 – 0.1	V
	Vo2	High-speed mode	0.1	-	AVCC0 – 0.1	V
Input offset voltage	Vioff	3σ	–10	-	10	mV
Open gain	Av		60	120	-	dB
Gain-bandwidth (GB) product	GBW1	Low-power mode	-	0.04	-	MHz
	GBW2	High-speed mode	-	1.7	-	MHz
Phase margin	PM	CL = 20 pF	50	-	-	deg
Gain margin	GM	CL = 20 pF	10	-	-	dB

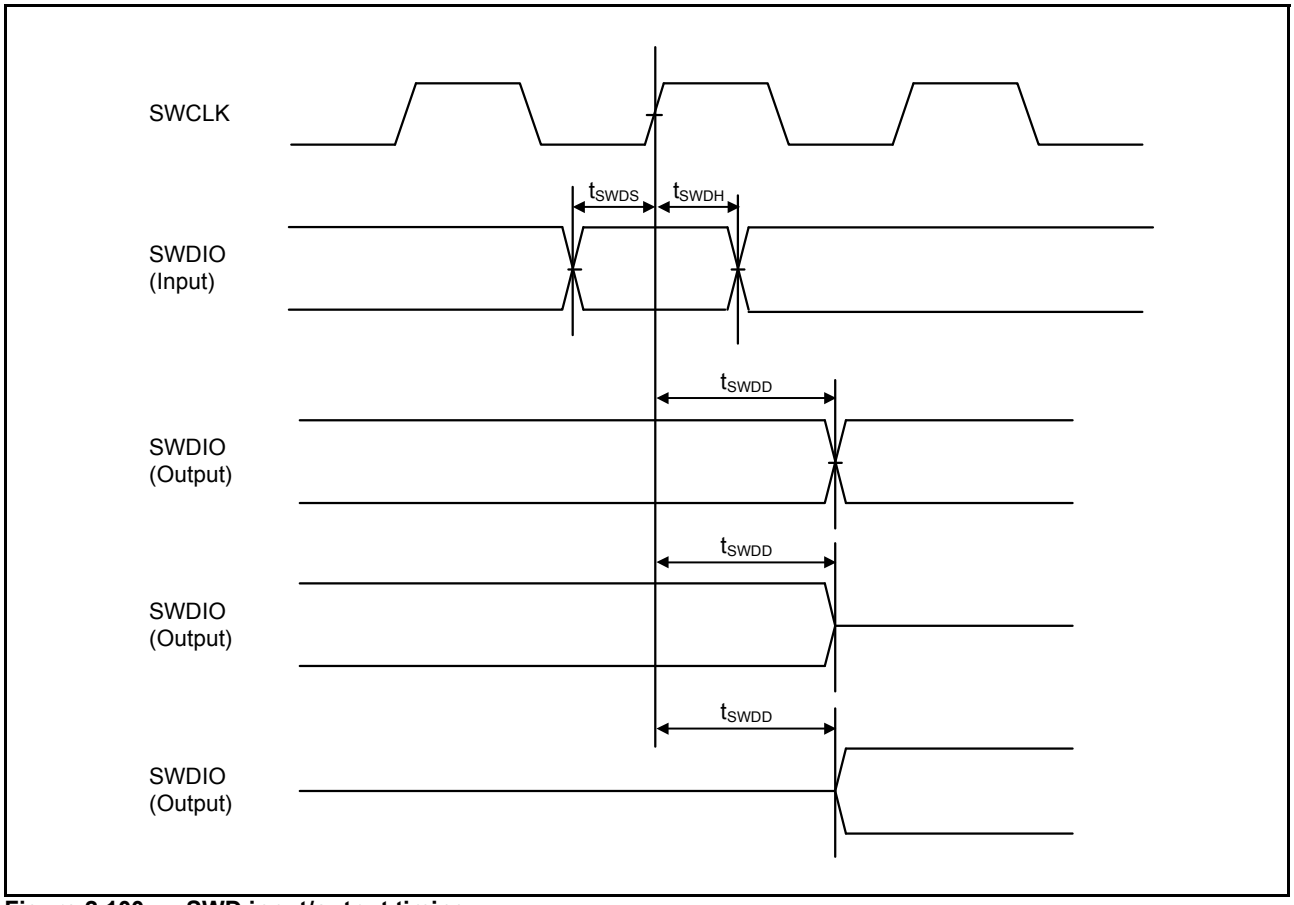
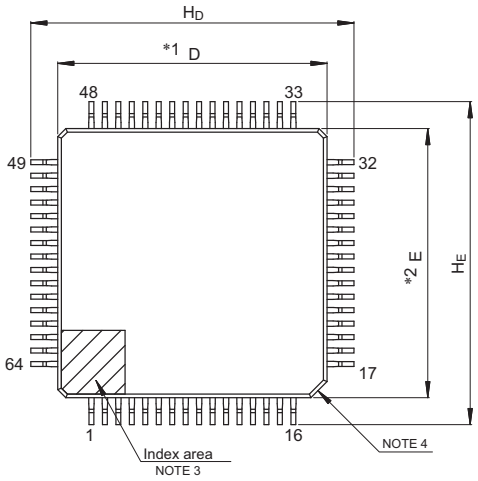
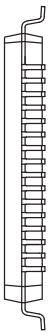


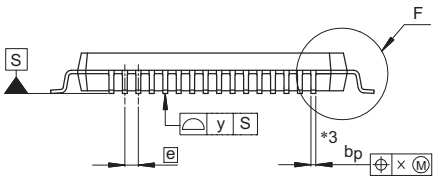
Figure 2.100 SWD input/output timing

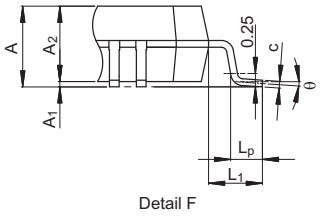
JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
P-LFQFP64-10x10-0.50	PLQP0064KB-C	—	0.3

Unit: mm









Detail F

NOTE)
1. DIMENSIONS "*1" AND "*2" DO NOT INCLUDE MOLD FLASH.
2. DIMENSION "*3" DOES NOT INCLUDE TRIM OFFSET.
3. PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE LOCATED WITHIN THE HATCHED AREA.
4. CHAMFERS AT CORNERS ARE OPTIONAL, SIZE MAY VARY.

Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
D	9.9	10.0	10.1
E	9.9	10.0	10.1
A_2	—	1.4	—
H_D	11.8	12.0	12.2
H_E	11.8	12.0	12.2
A	—	—	1.7
A_1	0.05	—	0.15
b_p	0.15	0.20	0.27
c	0.09	—	0.20
θ	0°	3.5°	8°
e	—	0.5	—
x	—	—	0.08
y	—	—	0.08
L_p	0.45	0.6	0.75
L_1	—	1.0	—

Figure 1.6 LQFP 64-pin

Revision History	S3A1 Microcontroller Group Datasheet

Rev.	Date	Summary
1.00	Oct 30, 2017	1st release
1.10	Mar 7, 2018	2nd release